

ISP624-1X, ISP624-2X, ISP624-4X
 ISP624-1, ISP624-2, ISP624-4



**LOW INPUT CURRENT
 PHOTOTRANSISTOR
 OPTICALLY COUPLED ISOLATORS**

APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form : -
 -STD
 - G form
 - SMD approved to CECC 00802
- Certified to EN60950 by the following
 Test Bodies :-
 Nemko - Certificate No. P96102022
 Fimko - Registration No. 192313-01..25
 Semko - Reference No. 9639052 01
 Demko - Reference No. 305969

DESCRIPTION

The ISP624-1, ISP624-2, ISP624-4 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

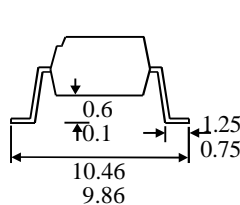
FEATURES

- Options :-
 10mm lead spread - add G after part no.
 Surface mount - add SM after part no.
 Tape&reel - add SMT&R after part no.
- High Current Transfer Ratio (50% min)
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- High BV_{CEO} (55Vmin)
- All electrical parameters 100% tested
- Low Input Current 0.5mA I_F

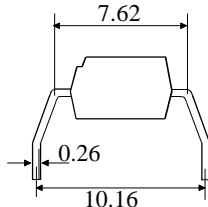
APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

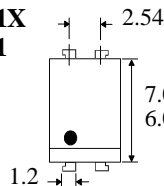
**OPTION SM
 SURFACE MOUNT**



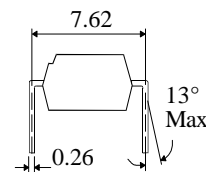
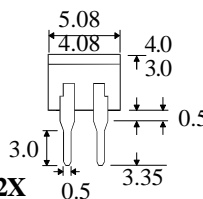
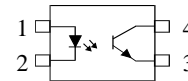
OPTION G



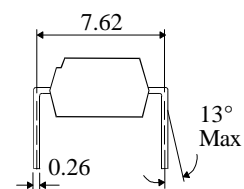
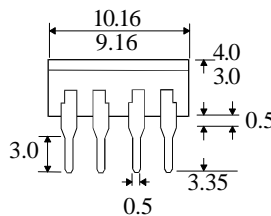
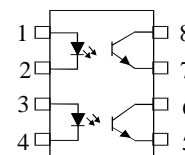
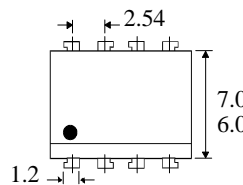
**ISP624-1X
 ISP624-1**



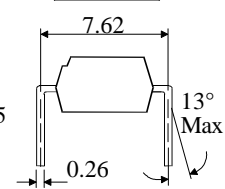
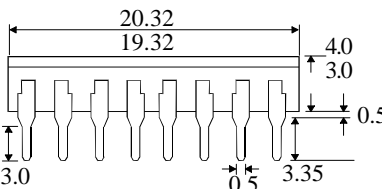
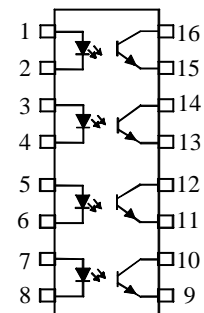
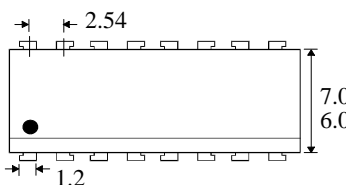
Dimensions in mm



**ISP624-2X
 ISP624-2**



**ISP624-4X
 ISP624-4**



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 Park View Industrial Estate, Brenda Road
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ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-55°C to + 125°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	50mA
Reverse Voltage	5V
Power Dissipation	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	55V
Emitter-collector Voltage BV_{ECO}	6V
Power Dissipation	150mW

POWER DISSIPATION

Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

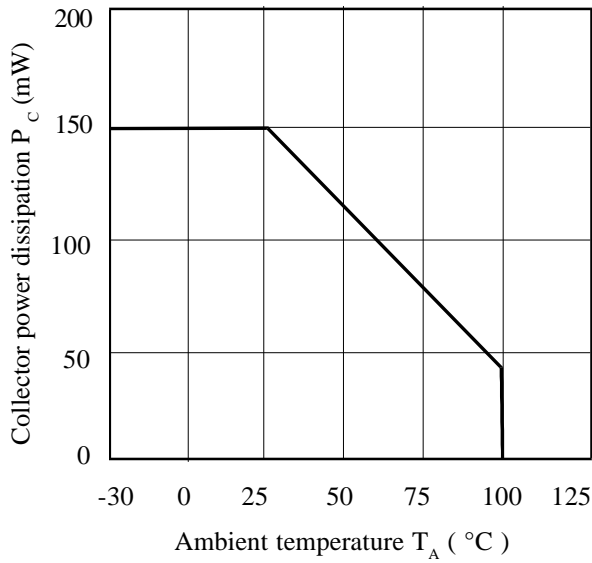
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION	
Input	Forward Voltage (V_F)	1.0	1.15	1.3	V	$I_F = 10\text{mA}$	
	Reverse Voltage (V_R)	5			V	$I_R = 10\mu\text{A}$	
	Reverse Current (I_R)			10	μA	$V_R = 5\text{V}$	
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	55			V	$I_C = 0.5\text{mA}$	
	Emitter-collector Breakdown (BV_{ECO})	6			V	$I_E = 100\mu\text{A}$	
	Collector-emitter Dark Current (I_{CEO})			100	nA	$V_{CE} = 24\text{V}$	
Coupled	Current Transfer Ratio (CTR) (Note 2) ISP624-1,ISP624-2,ISP624-4	100		1200	%	$1\text{mA } I_F, 0.5\text{V } V_{CE}$	
		50			%	$0.5\text{mA } I_F, 1.5\text{V } V_{CE}$	
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$			0.2	0.4	V	$1\text{mA } I_F, 0.5\text{mA } I_C$
						V	$1\text{mA } I_F, 1\text{mA } I_C$
	Input to Output Isolation Voltage V_{ISO}	5300			V_{RMS}	See note 1	
		7500			V_{PK}	See note 1	
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500\text{V}$ (note 1)	
	Rise Time tr		8		μs	$V_{CC} = 10\text{V}$,	
	Fall Time tf		8		μs	$I_C = 2\text{mA}, R_L = 100\Omega$	
	Turn-on Time ton		10		μs		
Turn-off Time toff		8		μs			

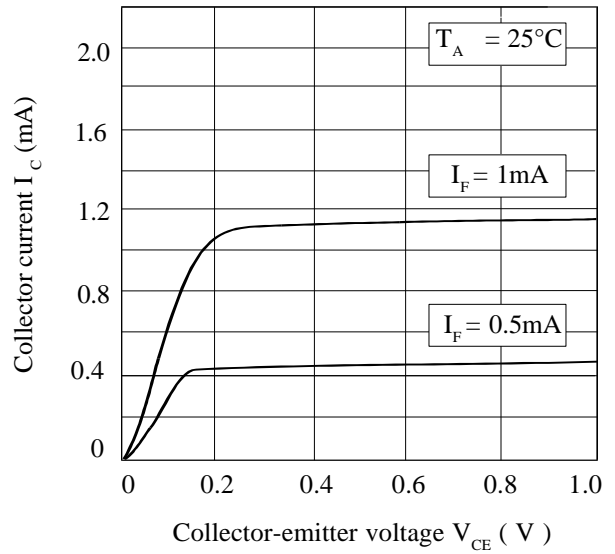
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

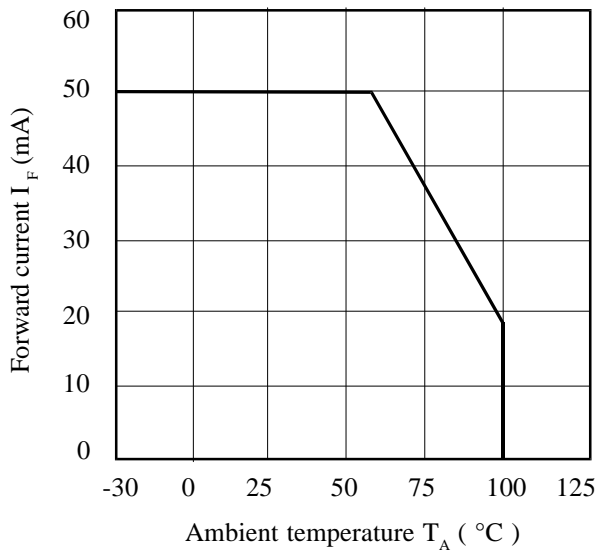
Collector Power Dissipation vs. Ambient Temperature



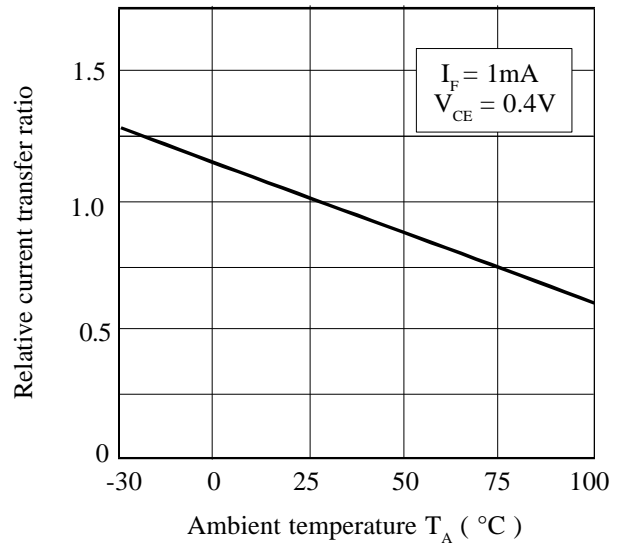
Collector Current vs. Low Collector-emitter Voltage



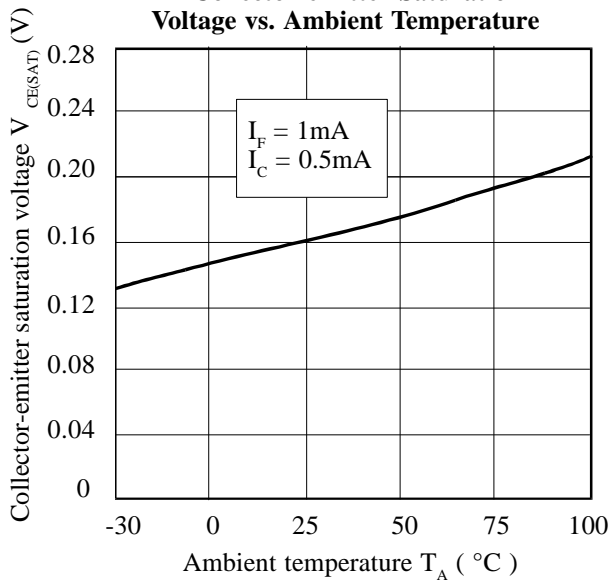
Forward Current vs. Ambient Temperature



Relative Current Transfer Ratio vs. Ambient Temperature



Collector-emitter Saturation Voltage vs. Ambient Temperature



Current Transfer Ratio vs. Forward Current

